

TO-220AB

DTP0455C www.din-tek.jp

RoHS

COMPLIANT

N-Channel 60 V (D-S) MOSFET

PRODUCT	RODUCT SUMMARY			
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^d	Q _g (Typ.)	
60	0.0047 at V_{GS} = 10 V	100	79	
	0.0054 at V _{GS} = 4.5 V	80	79	

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Power Supply
 - Secondary Synchronous Rectification
- DC/DC Converter

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G D S	S N-Channel MOSFET

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ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless oth	nerwise noted)			
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current ($T_1 = 150 \ ^{\circ}C$)	T _C = 25 °C	I _D	100 ^d	A	
	T _C = 70 °C	טי	80 ^d		
Pulsed Drain Current		I _{DM}	350		
Avalanche Current		I _{AS}	50		
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	170	mJ	
	T _C = 25 °C	D	125 ^b	W	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	– P _D –	3.0]	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Limit	Unit
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W
Junction-to-Case (Drain)	R _{thJC}	1	0/11

Notes:

a. Duty cycle ≤ 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•					
Drain-Source Breakdown Voltage	V _{DS}	$V_{DS} = 0 V, I_{D} = 250 \mu A$	60			V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1		3	v
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA
		$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$			50	μA
		$V_{DS} = 48 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 150 ^{\circ}\text{C}$			250	-
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10$ V, $V_{GS} = 10$ V	50			А
	P	V _{GS} = 10 V, I _D = 22 A		0.0047	0.0056	0
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 20 A		0.0054	0.0065	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		159		S
Dynamic ^b						
Input Capacitance	C _{iss}			13580		
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 20 V, f = 1 MHz		1805		pF
Reverse Transfer Capacitance	C _{rss}			298		
Total Gate Charge ^c	Qg			87	131	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 20$ V, $V_{GS} = 10$ V, $I_{D} = 20$ A		15.3		nC
Gate-Drain Charge ^c	Q _{gd}			12.2		
Gate Resistance	Rg	f = 1 MHz	0.5	2.7	5.4	Ω
Turn-On Delay Time ^c	t _{d(on)}			11	20	
Rise Time ^c	t _r	V_{DD} = 20 V, R_L = 2 Ω		7	14	
Turn-Off Delay Time ^c	t _{d(off)}	$\rm I_D \cong 10$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 1 Ω		45	68	ns
Fall Time ^c	t _f			7	14	
Drain-Source Body Diode Ratings a	nd Characteris	stics T _C = 25 °C ^b				
Continuous Current	۱ _S				100	
Pulsed Current	I _{SM}				350	A
Forward Voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V		0.72	1.2	V
Reverse Recovery Time	t _{rr}			42	63	ns
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 10 A, dl/dt = 100 A/μs		2.5	3.8	Α
Reverse Recovery Charge	Q _{rr}			52	78	nC

Notes:

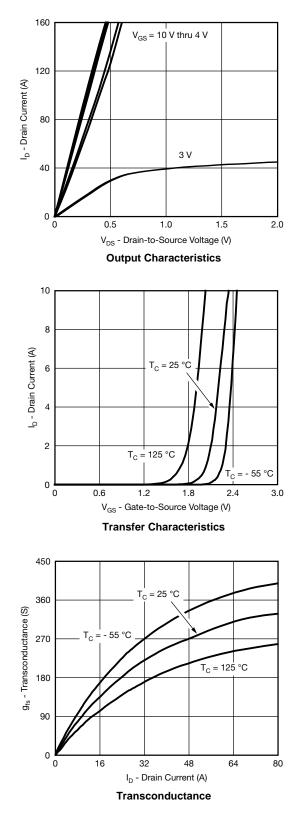
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

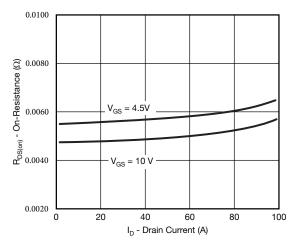
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

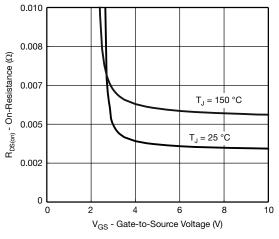


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

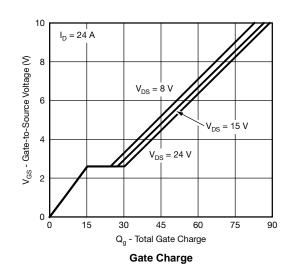




On-Resistance vs. Drain Current

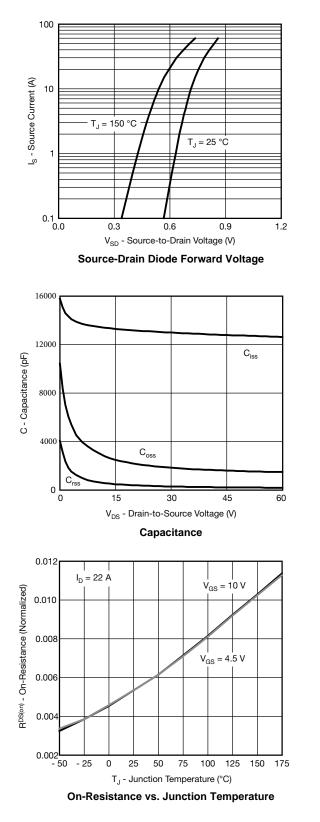


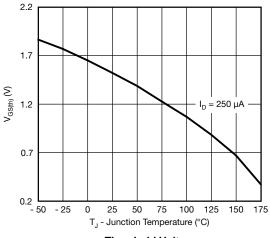




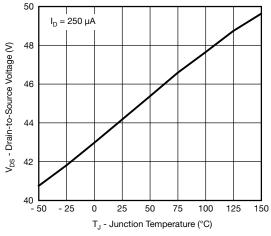


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

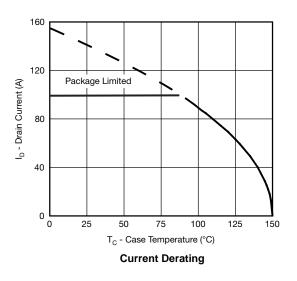




Threshold Voltage

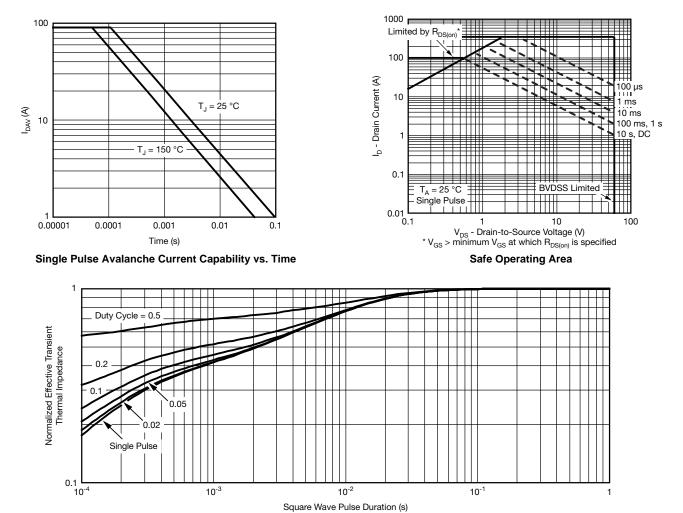


Drain Source Breakdown vs. Junction Temperature





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

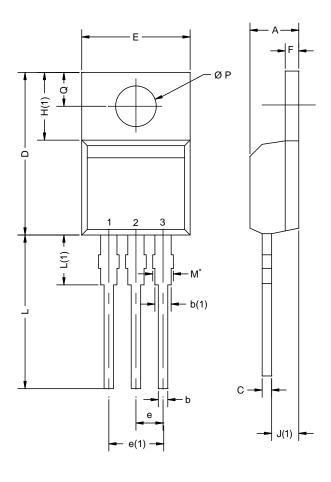


Normalized Thermal Transient Impedance, Junction-to-Case



Package Information www.din-tek.jp

TO-220AB



	MILLIN	IETERS	INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØΡ	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: X12- DWG: 547	0208-Rev. N, 1	08-Oct-12		

Notes

* M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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